

COMPOUND FIELD EFFECT POWER TRANSISTOR

μ PA1602

MONOLITHIC POWER MOS FET ARRAY

DESCRIPTION

The μ PA1602 is Monolithic N-channel Power MOS FET Array that built in 7 circuits designed for LED, Relay, Thermal Head, and so on.

FEATURES

- Direct driving is possible by standard Logic IC or Microcomputer.
(4 V driving is possible)
- Output Voltage: $V_o = 30$ V MAX.
Output Current: $I_o = 500$ mA MAX.
- Low Input Active
- $R_{on} = 3 \Omega$ TYP. at: $I_o = 150$ mA, $V_i = 4.5$ V
- Large Operation Temperature: -40 to $+85$ °C

ORDERING INFORMATION

Part Number	Package	Quality Grade
μ PA1602CX	16-Pin DIP	Standard
μ PA1602GS	16-Pin SOP	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

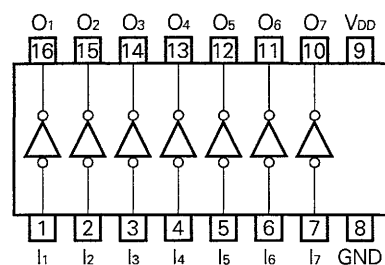
ABSOLUTE MAXIMUM RATINGS ($T_a = 25$ °C)

Supply Voltage	V_{DD}	-0.5 to $+7.0$	V
Output Voltage	$V_{O(DC)}$	30	V
Output Peak Voltage*	$V_{O(peak)}$	50	V
Input Voltage	V_i	-0.5 to $V_{DD} + 0.5$	V
Output Current (DC)	$I_{O(DC)}$	430	mA/unit
Output Current (pulse)**	$I_{O(pulse)}$	500	mA/unit
Input Current	I_i	± 10	mA/unit
Total Power Dissipation	P_T	1.0	W/PKG
Operating Temperature	T_{opt}	-40 to $+85$	°C
Storage Temperature	T_{stg}	-55 to $+150$	°C

* $PW \leq 10$ ms, Duty Cycle ≤ 10 %

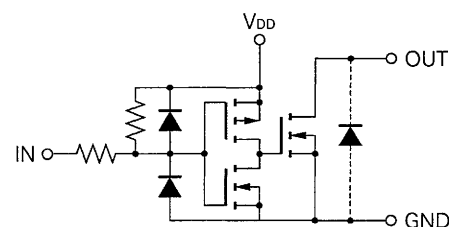
** $PW \leq 10$ ms, Duty Cycle ≤ 30 %

CONNECTION DIAGRAM



I : Input
O : Output
 V_{DD} : Supply Voltage

Equivalent Circuits (1/7 Circuit)



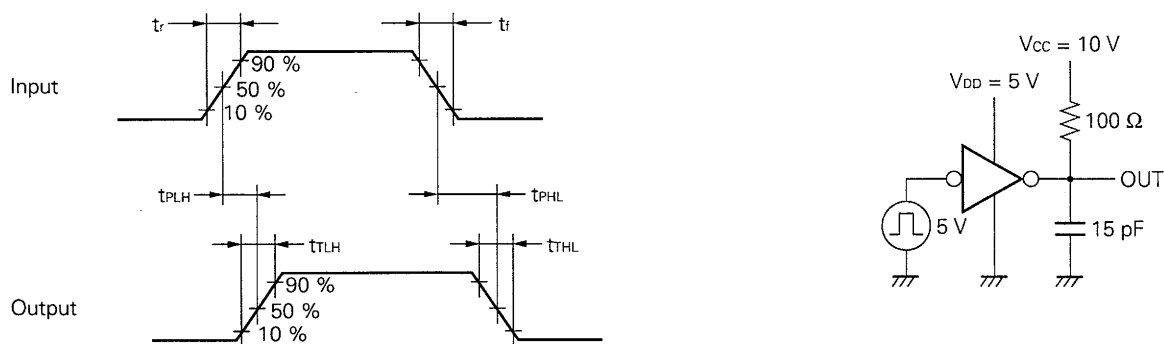
RECOMMENDED OPERATING CONDITIONS ($T_a = -40$ to $+85$ °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Supply Voltage	V_{DD}	4.5	5.0	5.5	V	
Output Voltage	$V_{O(DC)}$			24	V	
Output Current	$I_{O(DC)}$			270	mA/unit	DC, 1 circuit
	$I_{O(pulse)}$			200	mA/unit	PW ≤ 10 ms, Duty Cycle ≤ 25 %, 7 circuits
Input Voltage	V_I	0		5	V	
High-Level Input Voltage	V_{IH}	2			V	
Low-Level Input Voltage	V_{IL}			0.8	V	

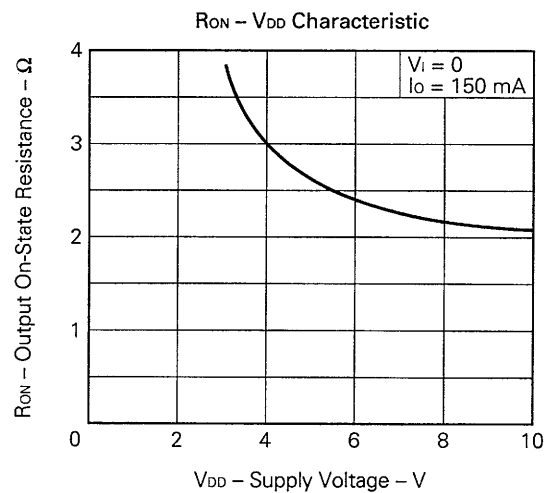
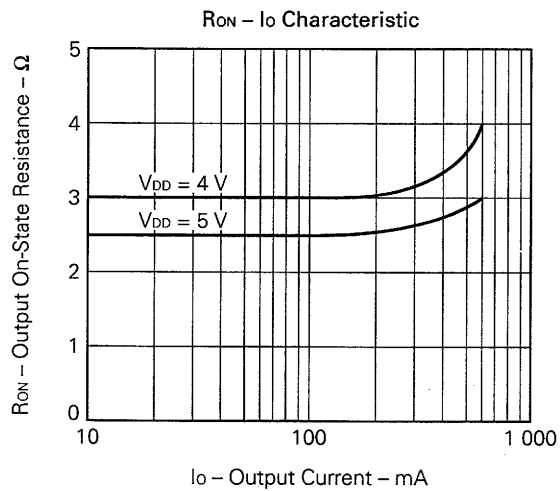
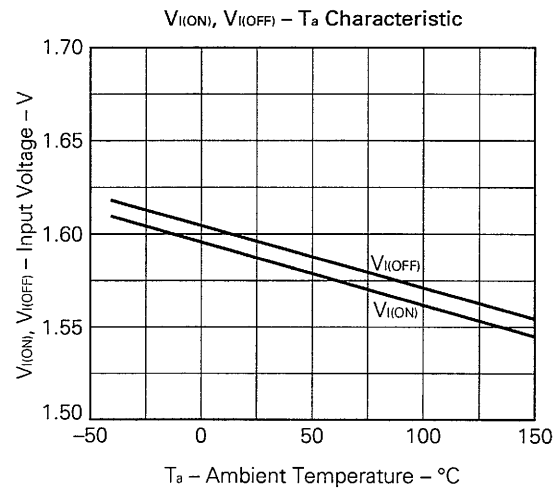
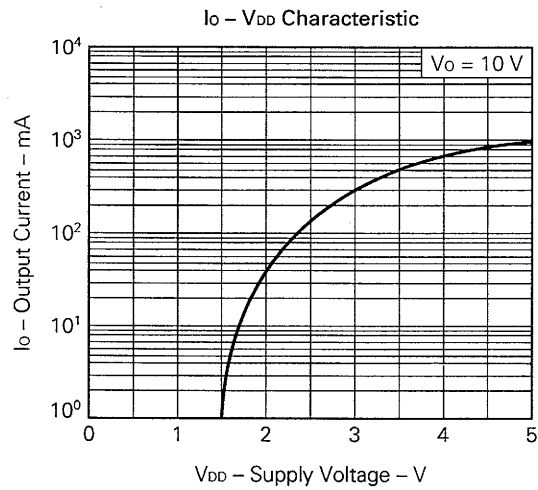
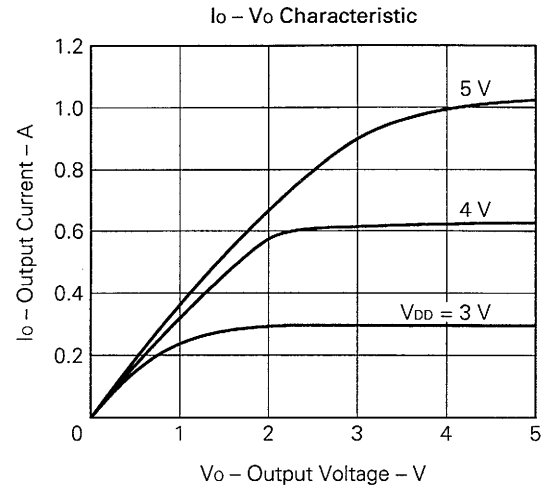
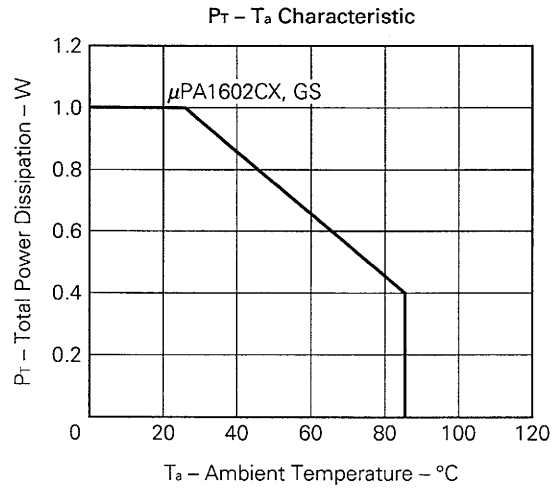
ELECTRICAL CHARACTERISTICS ($T_a = 25$ °C)

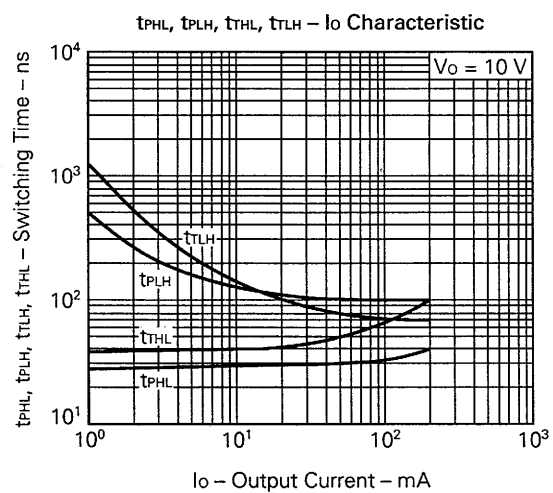
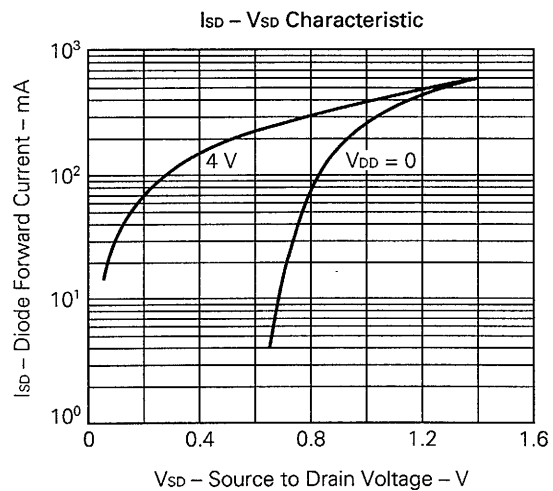
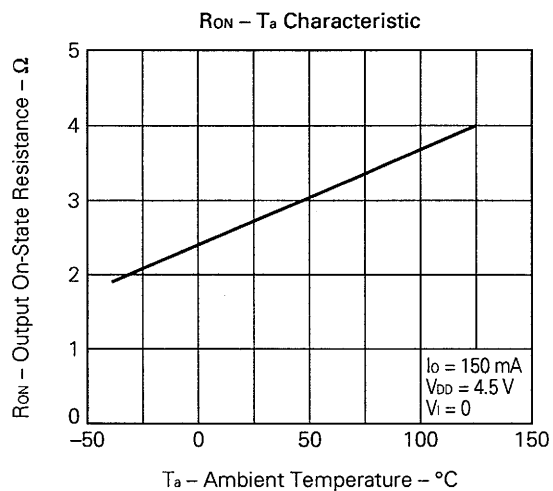
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Supply Current	$I_{DD(ON)}$			1	mA	$V_{DD} = 5.5$ V, $V_I = 0$
	$I_{DD(OFF)}$			10	μ A	$V_{DD} = 5.5$ V, $V_I = 5.5$ V
Output Leakage Current	$I_{O(OFF)}$			10	μ A	$V_{DD} = 5.5$ V, $V_I = 5.5$ V, $V_O = 30$ V
Output On-state Resistance	R_{on}		3	5.3	Ω	$V_{DD} = 4.5$ V, $V_I = 0$, $I_O = 150$ mA
Output On-state Voltage	$V_{O(ON)1}$			0.1	V	$V_{DD} = 4.5$ V, $V_I = 0$, $I_O = 10$ mA
	$V_{O(ON)2}$			1.0	V	$V_{DD} = 4.5$ V, $V_I = 0$, $I_O = 150$ mA
Input Voltage	$V_{I(OFF)}$	2			V	$V_{DD} = 5$ V, $V_O = 50$ V, $I_O = 100$ μ A
	$V_{I(ON)}$			0.8	V	$V_{DD} = 5$ V, $V_O = 0.8$ V, $I_O = 1$ mA
Input Current	I_{IH}			10	μ A	$V_{DD} = 5.5$ V, $V_I = 5.5$ V, $V_O = 0$ V
	I_{IL}			-1.0	mA	$V_{DD} = 5.5$ V, $V_I = 0$ V, $V_O = 50$ V
Input Capacitance	C_{in}		10		pF	$f = 1$ MHz
Delay Time	t_{PHL}		30		ns	$V_{CC} = 10$ V, $R_L = 100$ Ω $V_{DD} = 5$ V, $C_L = 15$ pF See Fig. 1
	t_{PLH}		110		ns	
Rise Time	t_{TLH}		80		ns	
Fall Time	t_{THL}		80		ns	

Fig. 1 Switching Wave Forms and Test Circuits



TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

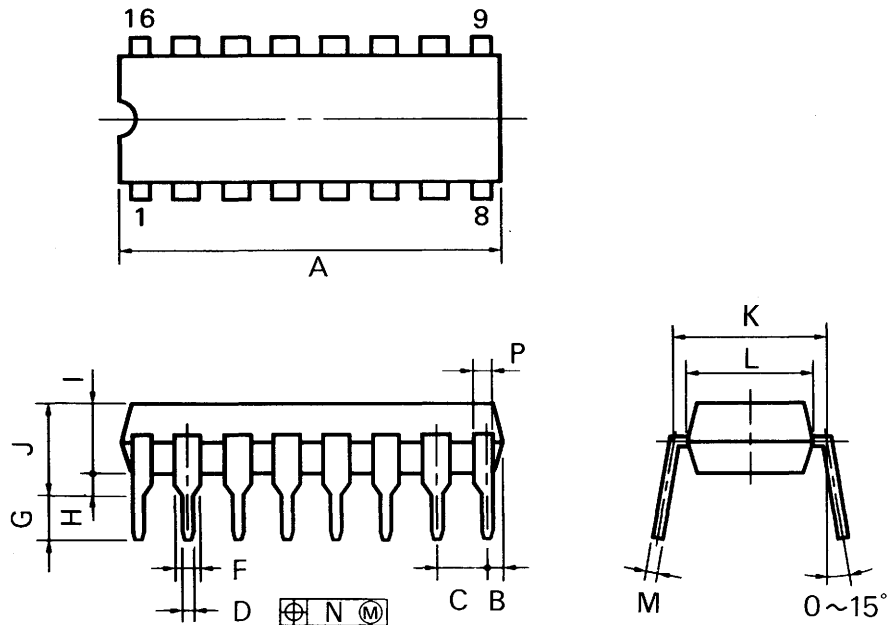




PACKAGE DIMENSIONS

• μPA1602CX

16PIN PLASTIC DIP (300 mil)



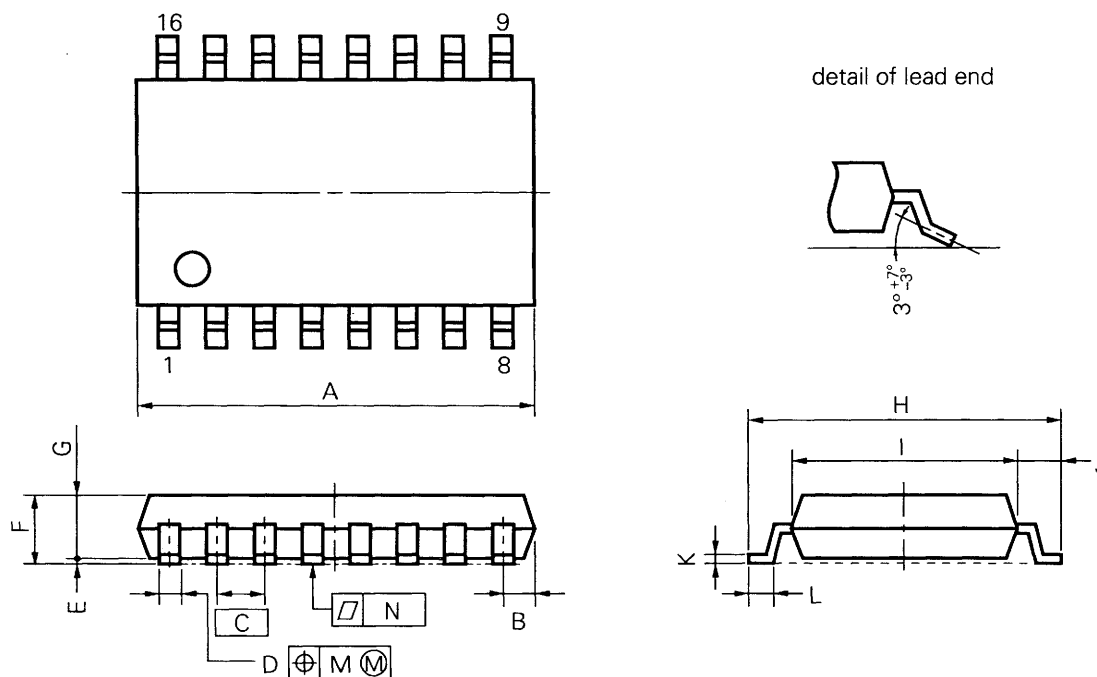
P16C-100-300A.C

NOTES

- 1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
A	20.32 MAX.	0.800 MAX.
B	1.27 MAX.	0.050 MAX.
C	2.54 (T.P.)	0.100 (T.P.)
D	0.50 ± 0.10	0.020 $\begin{smallmatrix} +0.004 \\ -0.005 \end{smallmatrix}$
F	1.2 MIN.	0.047 MIN.
G	3.5 ± 0.3	0.138 ± 0.012
H	0.51 MIN.	0.020 MIN.
I	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
K	7.62 (T.P.)	0.300 (T.P.)
L	6.4	0.252
M	0.25 $\begin{smallmatrix} +0.10 \\ -0.05 \end{smallmatrix}$	0.010 $\begin{smallmatrix} +0.004 \\ -0.003 \end{smallmatrix}$
N	0.25	0.01
P	1.0 MIN.	0.039 MIN.

• μPA1602GS
16 PIN PLASTIC SOP (300 mil)



P16GM-50-300B-3

ITEM	MILLIMETERS	INCHES
A	10.46 MAX.	0.412 MAX.
B	0.78 MAX.	0.031 MAX.
C	1.27 (T.P.)	0.050 (T.P.)
D	0.40 ^{+0.10} _{-0.05}	0.016 ^{+0.004} _{-0.003}
E	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071 MAX.
G	1.55	0.061
H	7.7±0.3	0.303±0.012
I	5.6	0.220
J	1.1	0.043
K	0.20 ^{+0.10} _{-0.05}	0.008 ^{+0.004} _{-0.002}
L	0.6±0.2	0.024 ^{+0.008} _{-0.009}
M	0.12	0.005
N	0.10	0.004

RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SEMICONDUCTOR DEVICES MOUNTING TECHNOLOGY MANUAL" (IEI-1207).

μPA1602GS

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 235 °C or below, Reflow time: 30 seconds or below (210 °C or higher), Number of reflow process: 2 or below, Exposure limit*: None	IR35-00-2
VPS	Peak package's surface temperature: 215 °C or below, Reflow time: 40 seconds or below (200 °C or higher), Number of reflow process: 2 or below, Exposure limit*: None	VP15-00-2
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below, Number of flow process: 1, Exposure Limit*: None	WS60-00-1

*: Exposure limit before soldering after dry-pack package is opened.

Storage conditions: 25 °C and relative humidity at 65 % or less.

Note: Do not apply more than a single process at once, except for "Partial heating method".

TYPES OF THROUGH HOLE MOUNT DEVICE

μPA1602CX

Soldering process	Soldering conditions	Symbol
Wave soldering	Solder temperature: 260 °C or below, Flow time: 10 seconds or below	

Reference

Document name	Document No.
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207
Semiconductor device package manual	IEI-1213
SMD surface mount technology manual	IEI-1207

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The devices listed in this document are not suitable for use in aerospace equipment, submarine cables, nuclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or they intend to use "Standard" quality grade NEC devices for applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation.

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.